Form PTO-1595 (Rev. 10/02)	07-16-2003	U.S. DEPARTMENT OF COMMER
OMB No. 0651-0027 (exp. 6/30/2005)		U.S. Patent and Trademark Off
	100409457	Atty. Docket No. TSMC2003-04
To the honorable Commissioner of Pa		ginal documents or copy thereof.
Name of conveying party(ies):  Yee-Chia Yeo Fu-Liang Yang	27-/X	dress of receiving party(ies) an Semiconductor Manufacturing Compar
I d Liang rang	Internal Add	ress:
	Street Addre	ess: No. 6, Li-Hsin Rd. 6
	Science-Base	ed Industrial Park
Additional name(s) of conveying party(ies) attached?	Yes X No City: <u>Hsin-Chu</u>	
Nature of conveyance:	State: <u>Taiwan</u>	Zip: <u>300-77</u>
X Assignment Merger		
Security Agreement Change	of Name	
Other		
Execution Date: Yeo - 6/26/03; Yang - 6/26/0	Additional name(s)	& address(es) attached? Yes X
4. Application number(s) or patent number(s)	/UbUKKO /	
If this document is being filed together with a new a  A. Patent Application No.(s)	application, the execution date of the	
	tional numbers attached? Yes	X No
Name and address of party to whom corres		
concerning document should be mailed:		of applications and patents involved: 1
Name: Steven H. Slater	7. Total fee (37	CFR 3.41) \$ <u>40.00</u>
Slater & Matsil, L.L.P.	Enclose	ed
Street Address: 17950 Preston Rd.		
Suite 1000	<b>L</b>	zed to be charged to deposit account
City: <u>Dallas</u> State: <u>Texas</u> Zip: <u>7</u>	8. Deposit accor	unt number:
2003 DBYRNE 00000073 501065 10608287		50-1065
:80P1 40.00 DA	(Attach duplicate c	opy of this page if paying by deposit account)
	DO NOT USE THIS SPACE	
9. Statement and signature.  To the best of my knowledge and belief, to list a true copy of the original document.	the foregoing information is true ar	nd correct and any attached copy
Ira S. Matsil Reg. No. 35,272	Wy I MAP	June 27, 2003
Name of Person Signing	VSignature uding cover sheet, attachments, and do	Date

P.04

ATTORNEY DOCKET NO. TSMC2003-0421

## **ASSIGNMENT**

WHEREAS, I, the undersigned inventor (or one of the undersigned joint inventors), of residence as listed, having invented certain new and useful improvements as below entitled, for which application for United States Letters Patent is made, the said application having been executed on the date set forth below; and

WHEREAS, Taiwan Semiconductor Manufacturing Company, Ltd. (TSMC), a corporation organized and existing under the laws of Taiwan, the Republic of China, with its principal office at No. 6, Li-Hsin Rd. 6, Science-Based Industrial Park, Hsin-Chu, Taiwan 300-77, R.O.C., is desirous of acquiring my entire right, title and interest in and to the said invention, and to the said application and any Letters Patent that may issue thereon in the United States and all other countries throughout the world;

NOW, THEREFORE, for good and valuable consideration, the receipt of which is hereby acknowledged, I hereby sell and assign to the said TSMC, its successors and assigns, my entire right, title and interest in and to the said invention and in to the said application and all patents which may be granted therefor, and all divisions, reissues, substitutions, continuations, and extensions thereof; and I hereby authorize and request the Commissioner for Patents to issue all patents for said invention, or patent resulting therefrom, insofar as my interest is concerned, to the said TSMC, as assignee of my entire right, title and interest. I declare that I have not executed and will not execute any agreement in conflict herewith.

I also hereby sell and assign to TSMC, its successors and assigns, my foreign rights to the invention disclosed in said application, in all countries of the world, including, but not limited to, the right to file applications and obtain patents under the terms of the International Convention for the Protection of Industrial Property, and of the European Patent Convention, and further agree to execute any and all patent applications, assignments, affidavits, and any other papers in connection therewith necessary to perfect such patent rights.

I hereby further agree that I will communicate to said TSMC, or to its successors, assigns, and legal representatives, any facts known to me respecting said invention or the file history thereof, and at the expense of said assignee company, testify in any legal proceedings, sign all lawful papers, execute all divisional, continuation, reissue and substitute applications, make all lawful oaths, and generally do everything possible to aid said TSMC, its successors, assigns and nominees to obtain and enforce proper patent protection for said invention in all countries.

IN WITNESS WHEREOF, I hereunto set my hand and seal this day and year;

TITLE OF INVENTION	Structure and Method for Forming the Gate Electrode in a Multiple-Gate Transistor	
SIGNATURE OF INVENTOR AND NAME	Yushia Yes. Yee-Chia Yeo	to langed any Fu-Liang Yang
DATE	Tune 26, 2003.	Ine 26, 2003.
RESIDENCE (City, County, State)	Hsin-Chu, Taiwan 300-77 R.O.C.	Hsin-Chu, Taiwan R.O.C.

PATENT
RECORDED: 06/27/2003 REEL: 014259 FRAME: 0370